NSN 5961-01-587-5783



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-587-5783 **Inclosure Material:** Metal and glass **Overall Length:** Between 1.022 inches and 1.253 inches **Overall Width:** 0.437 inches **Function For Which Designed:** Voltage regulator **End Application:** Missile, minuteman iii, Igm-30 **Mounting Facility Quantity: Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): **Thread Size:** 0.169 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 regulator voltage **Current Rating Per Characteristic:** 70.00 milliamperes voltage regulator diode current **Power Rating Per Characteristic:** 10.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf and unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud

rtab, solder lag and r timeaded st
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0